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(54) **DISPLAY APPARATUS AND METHOD FOR MANUFACTURING DISPLAY APPARATUS**

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(57)

ABSTRACT

A display apparatus having an image capturing function is provided. A display apparatus or an image capturing device with a high aperture ratio is provided. The display apparatus includes a first light-emitting element and a light-receiving element. The first light-emitting element includes a first pixel electrode, a first organic layer, and a common electrode. The light-receiving element includes a second pixel electrode, a second organic layer, and the common electrode. The first organic layer includes a first light-emitting layer, and the second organic layer includes a photoelectric conversion layer. A first layer and a second layer are included in a region between the first light-emitting element and the light-receiving element. The first layer overlaps with the second organic layer and the second pixel electrode and contains a material identical to a material of the first organic layer. The second layer overlaps with the first organic layer and the first pixel electrode and contains a material identical to a material of the second organic layer. In the region between the first light-emitting element and the light-receiving element, an end portion of the first organic layer and an end portion of the first layer face each other and an end portion of the second organic layer and an end portion of the second layer face each other.

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